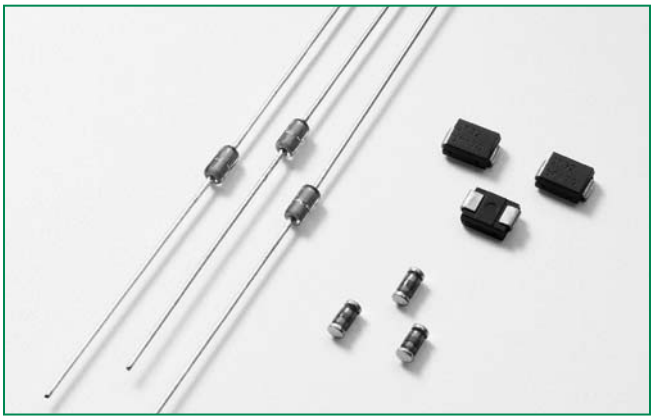
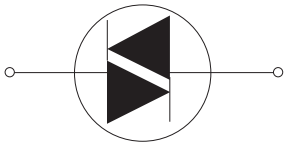
RoHS HTxxx & HTMxxx & STxxx Series



Schematic Symbol



Applications

DIACs are used to trigger Triacs and SCRs in phase control circuits for lamp dimming, universal motor speed control, and heat control. They are used also for triggering transistors in solid state ballast lighting controls.

Description

The HTM, HT, and ST series of bilateral trigger DIACs offer a range of voltage characteristics from 27V to 70V. A DIAC semiconductor is a full-wave or bidirectional Thyristor. It is triggered from a blocking state to a conduction state for either polarity of applied voltage whenever the amplitude of applied voltage exceeds the breakover voltage of the DIAC.

Features & Benefits

- RoHS compliant
- Bilateral triggering device
- Glass-passivated junctions
- Wide voltage range selections
- Long-term reliability
- Parameter stability
- Reliable barrier against junction contamination

ST Series:

- Epoxy SM package (DO-214)
- High-temperature, solder bonded die attachment

HTM/HT Series:

- MINIMELF/DO-35 trigger package

Absolute Maximum Ratings

Symbol	Parameter	Test Conditions	Min	Max	Unit
I_{TRM}	Pulse On-State Current	120PPS, $T_A \leq 40°C$ pulse width = 10 µS		2	A
				1.5(*)	
T_S	Storage Temperature Range		-40	+125	°C
T_J	Operating Junction Temperature		-40	+125	°C
$P_{D(AV)}$	Device Power Dissipation	T_A = -40°C to +40°C		See Product Selector Table	mW

(*)Only Applies to HT-60

Notes:

1. Service Dissipation (at T_A = -40°C to +40°C): 250mW for DO-35 and MINIMELF/SOD-80 and 300mW for DO214
2. Above +40°C, Derate: 3.6mW/°C for DO-35 and MINIMELF/SOD-80 and 3mW/°C for DO214

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Electrical Characteristics (T_J = 25°C, unless otherwise specified)

Symbol	Description	Test Conditions	Min	Max	Unit
V_{BO}	Breakover/Trigger Voltage	50/60Hz Sine Wave	See Product Selector Table	See Product Selector Table	V
ΔV_{BO}	Breakover Voltage Symmetry	$+V_{BO}$ to $-V_{BO}$		2(Note 1)	V
V_{BB}	Δ Breakback Voltage(Note 4)	V_{BO} to V_{10mA}	5		V
		V_{BO} to V_{6mA}(*)	15		V
$V_{BB\ (DYN)}$	Dynamic Δ Breakback Voltage(Notes 2 & 3)	120 PPS	10		V
I_{BO}	Breakover Current	50/60Hz Sine Wave		15	µA

(*) Only Applies to HT-60

Electrical Characteristic Notes:

1. Breakover voltage symmetry as close as 1V is available from the factory for these products.
2. See Figure 4 and Figure 5 for test circuit and waveforms.
3. Typical switching time is 900 nano-seconds measured at I_{PK} (Figure 4) across a 20 Ω resistor (Figure 5). Switching time is defined as rise time of I_{PK} between the 10% to 90% points
4. See V-I Characteristics

Static Characteristics - Not Applicable

Product Selector

Part Number	Package Availability			V_{BO}	
	MINIMELF	DO-35	DO-214	MIN	MAX
XX-32	—	HT-32	ST-32	27V	37V
XX-32A/ 5761	—	HT-32A	—	28V	36V
XX-32B/ 5761A	HTM-32B	HT-32B	ST-32B	30V	34V
XX-34B	—	HT-34B	ST-34B	32V	36V
XX-35	—	HT-35	ST-35	30V	40V
XX-36A/ 5762	—	HT-36A	ST-36A	32V	40V
XX-36B	—	HT-36B	ST-36B	34V	38V
XX-40	—	HT-40	ST-40	35V	45V
XX-60	—	HT-60	—	56V	70V

"XX" = HTM for MINIMELF
HT for DO-35
ST for DO-214

Thermal Resistances

Symbol	Description	Test Conditions		Value	Unit
$R_{\theta(J-L)}$	Junction to Lead	Maximum Lead Temperature: 85°C	DO-35	100	°C/W
		Maximum Lead Temperature: 90°C	DO-214	65*	°C/W
		Maximum Lead Temperature: 87°C	MINIMELF	75	°C/W
$R_{\theta(J-A)}$	Junction to Ambient	Free-Air	DO-35	278	°C/W

* Mounted on 1 cm^2 copper foil surface; two-ounce copper foil

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Figure 1: V-I Characteristics

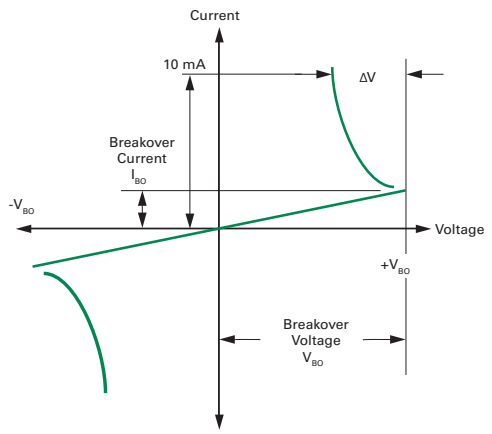


Figure 2: Typical DIAC/Triac Full-wave Phase Control Circuit

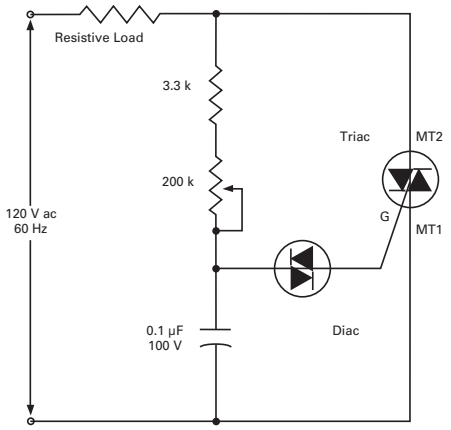


Figure 3: Repetitive Peak On-state Current vs. Pulse Duration

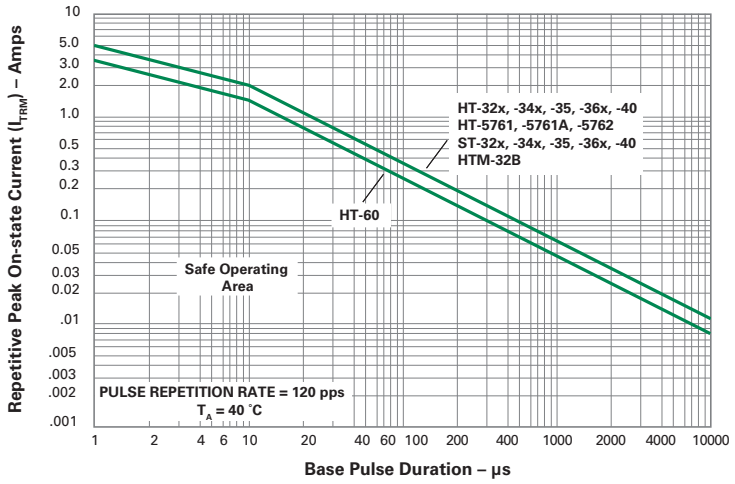


Figure 4: Normalized V_{BO} Change vs. Junction Temperature

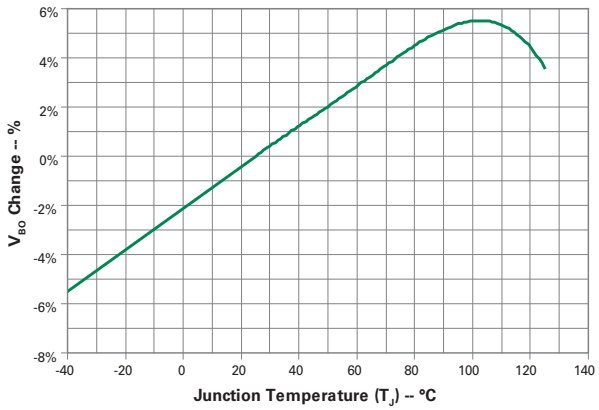
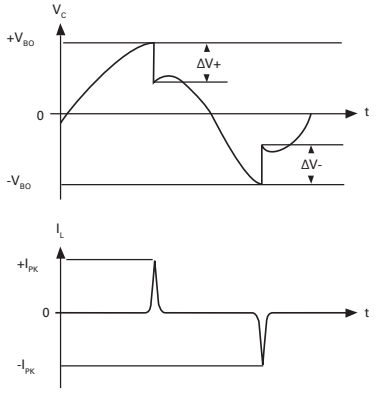


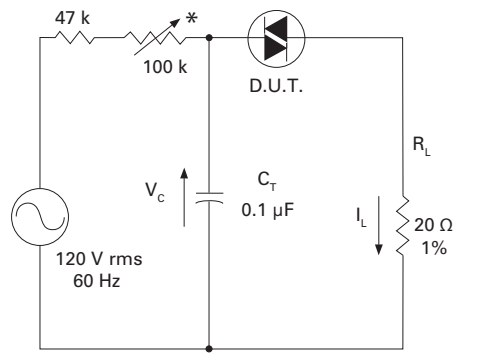
Figure 5: Test Circuit Waveforms (Refer to Figure 5)



Typical pulse base width is 10 µs

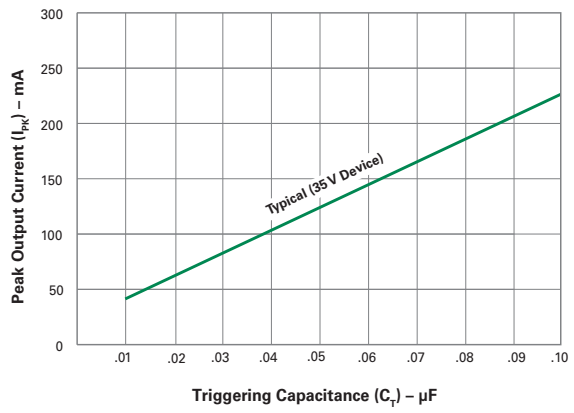
DIACs

Figure 6: Circuit Used to Measure DIAC Characteristics (Refer to Figure 4)



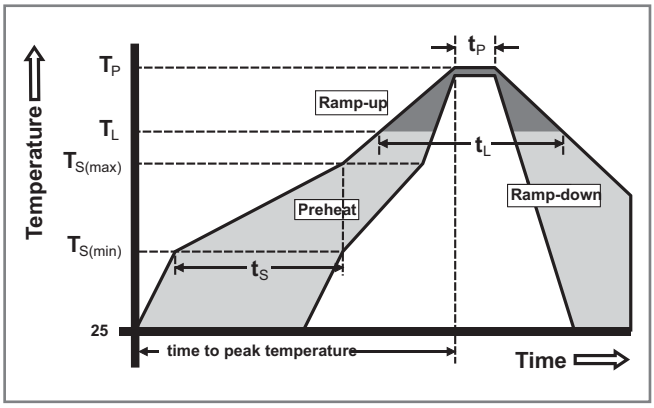
*Adjust for one firing in each half cycle. D.U.T. = Diac

Figure 7: Peak Output Current vs. Triggering Capacitance (Per Figure 5 with R_L of 20 Ω)



Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	-Temperature Min ($T_{s(min)}$)	150°C
	-Temperature Max ($T_{s(max)}$)	200°C
	-Time (min to max) (t_s)	60 – 190 secs
Average ramp up rate (Liquidus Temp (T_L) to peak		5°C/second max
$T_{S(max)}$ to T_L - Ramp-up Rate		5°C/second max
Reflow	-Temperature (T_L) (Liquidus)	217°C
	-Time (min to max) (t_s)	60 – 150 seconds
Peak Temperature (T_P)		260 °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T_P)		8 minutes Max.
Do not exceed		280°C



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Physical Specifications

Terminal Finish	100% Matte-Tin Plated/ Pb-Free Solder Dipped
Body Material	DO-214: UL recognized epoxy meeting flammabilty classification 94V-0. DO-35/MINIMELF: Glass case body
Lead Material	DO-214: Copper Alloy DO-35/MINIMELF: Copper Clad Iron

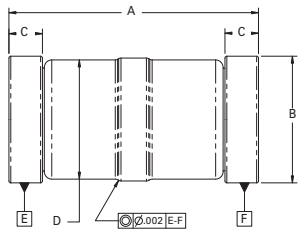
Design Considerations

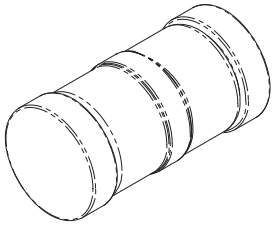
Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Overheating and surge currents are the main killers of DIACs. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Reliability/Environmental Tests

Test	Specifications and Conditions
High Temperature Voltage Blocking	MIL-STD-750, M-1040, Cond A Applied 80% of Rated Min V_{BO} (VAC-peak) @ 125°C for 1008 hours
Temperature Cycling	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time
Temperature/ Humidity	EIA / JEDEC, JESD22-A101 1008 hours; 80% of Rated Min V_{BO} (V_{DC}): 85°C; 85% rel humidity
High Temp Storage	MIL-STD-750, M-1031,1008 hours; 150°C
Low-Temp Storage	1008 hours; -40°C
Thermal Shock	MIL-STD-750, M-1056 10 cycles; 0°C to 100°C; 5-min dwell time at each temperature; 10 sec (max) transfer time between temperature
Autoclave	EIA / JEDEC, JESD22-A102 168 hours (121°C at 2 ATMs) and 100% R/H
Resistance to Solder Heat	MIL-STD-750 Method 2031
Solderability	ANSI/J-STD-002, category 3, Test A
Lead Bend	MIL-STD-750, M-2036 Cond E
Burn-in	1 firing per 1/2 cycle, 168 hours

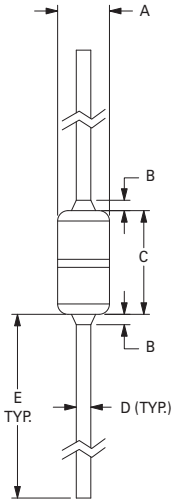
Dimensions – MINIMELF / SOD-80 (MM Package)





Dimensions	Inches			Millimeters		
	Min	Typ	Max	Min	Typ	Max
A	0.125	0.134	0.142	3.18	3.40	3.61
B	0.066	0.068	0.070	1.68	1.73	1.78
C	0.012	0.018	0.020	0.30	0.46	0.51
D	—	0.063	—	—	1.60	—

Dimensions – DO-35 (Y Package)



Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A (Note 1)	0.060	0.090	1.530	2.280
B (Note 2)		0.015		0.381
C (Note 1)	0.135	0.165	3.430	4.190
D	0.018	0.022	0.458	0.558
E	1.000		25.400	

Notes:
1. Package contour optional within dimensions A and C. Slugs, if any, shall be included within this cylinger but shall not be subject to the minimum limit of Dimention A.
2. Lead diameter is not controlled in this zone to allow for flash, lead finish build-up and minor irregularities other than slugs.

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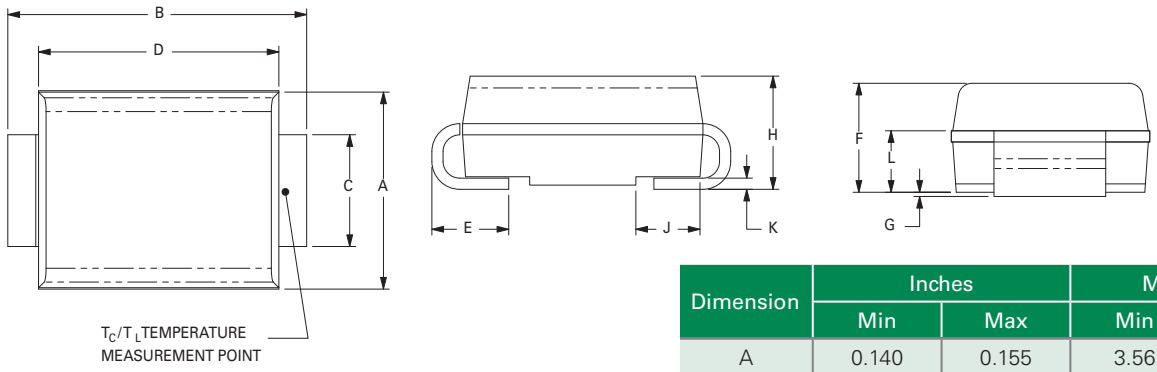
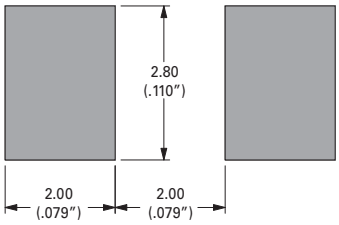
Dimensions – DO-214 (S Package)





Recommended Soldering Pad Outline
(Reference Only)

Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.140	0.155	3.56	3.94
B	0.205	0.220	5.21	5.59
C	0.077	0.083	1.96	2.11
D	0.166	0.180	4.22	4.57
E	0.036	0.063	0.91	1.60
F	0.066	0.083	1.67	2.11
G	0.004	0.008	0.10	0.20
H	0.077	0.086	1.96	2.18
J	0.043	0.053	1.09	1.35
K	0.008	0.012	0.20	0.30
L	0.039	0.049	0.99	1.24

Packing Options

Part Number	Marking	Package	Weight/ Unit	Packing Mode	Base Quantity	Quantity	
						Reel	Box
HTM-xxxRP	—	MINIMELF	0.040g	Tape & Reel	5000	2500	—
HT-xxxRP	—	DO35	0.150g	Tape & Reel	5000	5000	—
HT-xxx	—	DO35	0.150g	Bulk	5000	—	5000
ST-xxxRP	STxxx	DO214	0.075g	Tape & Reel	2500	2500	—

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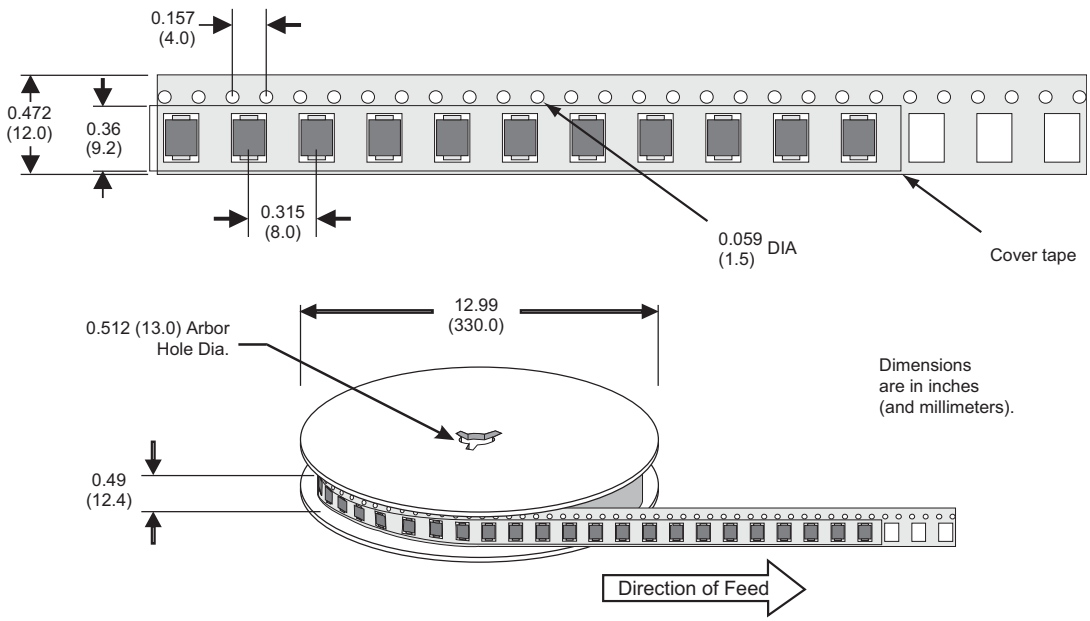
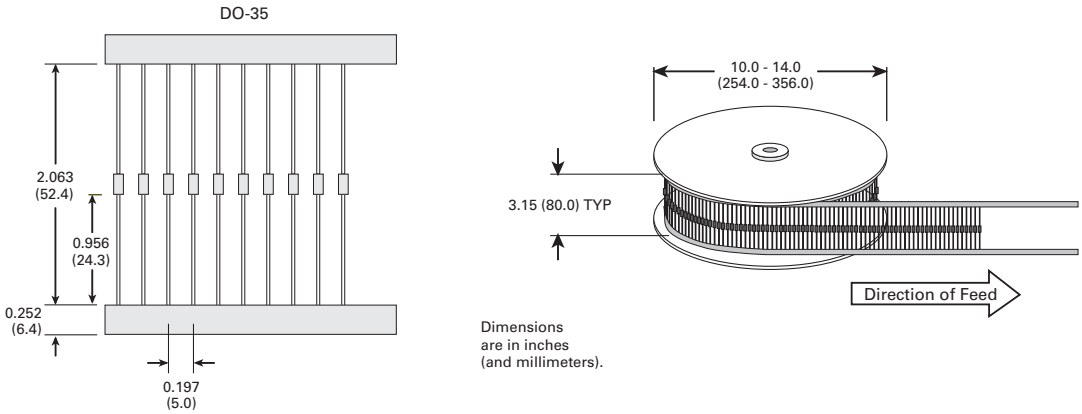
DO-214 Embossed Carrier Reel Pack (RP) Specifications

Meets all EIA-481-1 Standards



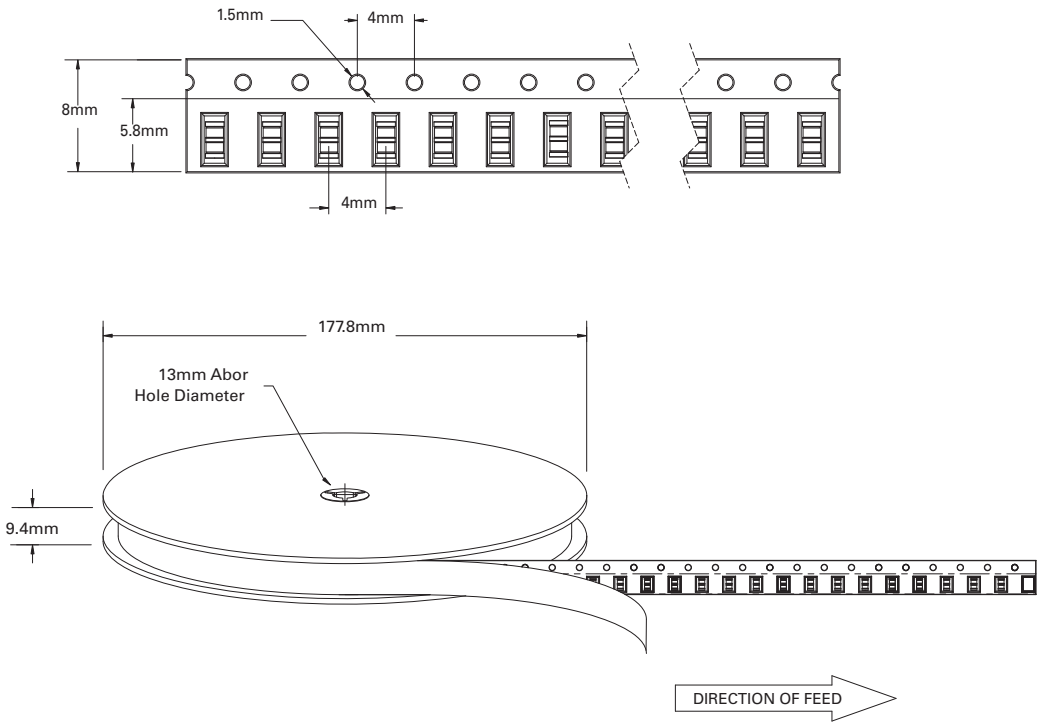
DO-35 Reel Pack (RP) Specifications

Meets all EIA-296 Standards



DIACs

MINIMELF Reel Pack (RP) Specifications



Part Numbering System

x T M xxxx xx

Package Type:
H = DO-35 (with leads) or MINIMELF (no leads)
S = DO-214

Device Type:
T = DIAC

Package Type Designator:
M: MINIMELF
(surface mount version without leads)

Packaging:
Blank = Bulk Pack
RP = Reel Pack

Voltage Range:
32= 27V to 37V
32A/5761= 28V to 36V
32B/5761A= 30V to 34V
34B= 32V to 36V
35= 30V to 40V
36A/5762= 32V to 40V
36B= 34V to 38V
40= 35V to 45V
60= 56V to 70V

Part Marking System

DO-35 & MINIMELF: No marking

DO-214:

First Line: Part Number
Second Line: Date Code

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- Индивидуальный подход
- Гибкое ценообразование

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